

Excellent Integrated System Limited

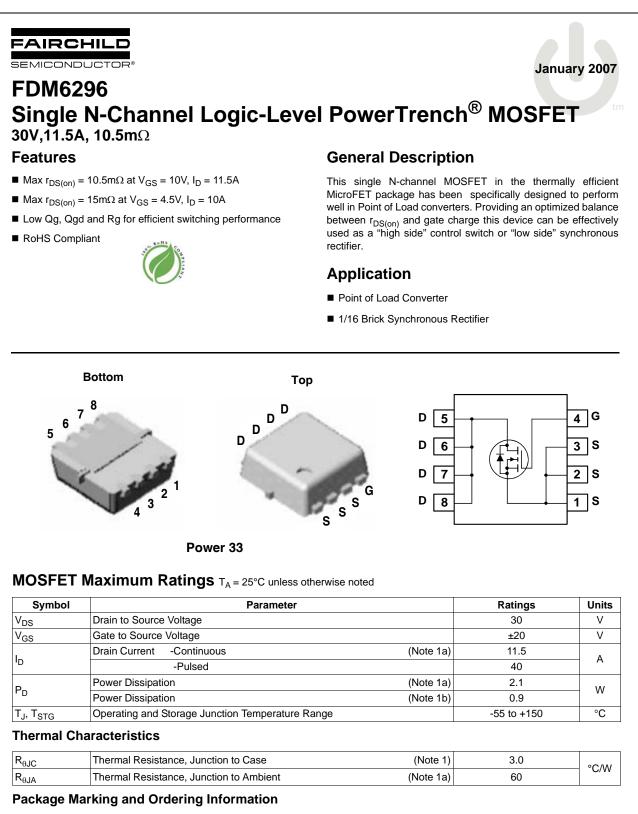
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Fairchild Semiconductor FDM6296

For any questions, you can email us directly: <u>sales@integrated-circuit.com</u>





Device Marking	Device	Package	Reel Size	Tape Width Quantit	
6296	FDM6296	Power 33	7"	8mm	3000 units

©2006 Fairchild Semiconductor Corporation FDM6296 Rev.E FDM6296 Single N-Channel Logic-Level PowerTrench $^{ extsf{m}}$ MOSFE1



Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	30			V	
ΔΒV _{DSS} ΔΤ _J	Breakdown Voltage Temperature Coefficient	$I_D = 250\mu A$, referenced to $25^{\circ}C$		29		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24V, V_{GS} = 0V$			1	μA	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA	
On Chara	cteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \mu A$	1	1.9	3	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to $25^{\circ}C$		-5		mV/°C	
r _{DS(on)} Stati		V _{GS} = 10V, I _D = 11.5A		8.7	10.5		
	Static Drain to Source On Resistance	$V_{GS} = 4.5V, I_{D} = 10A$		10.6	15	mΩ	
		$V_{GS} = 10V, I_D = 11.5A, T_J = 125^{\circ}C$		13	17		
9fs	Forward Transconductance	$V_{DS} = 5V, I_{D} = 11.5A$		47		S	
Dynamic	Characteristics						
C _{iss}	Input Capacitance			1507	2005	pF	
C _{oss}	Output Capacitance	── V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		415	555	pF	
C _{rss}	Reverse Transfer Capacitance			128	170	pF	
Rg	Gate Resistance	V_{DS} = 15mV, f = 1MHz		1.1		Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			10	20	ns	
t _r	Rise Time	$V_{DD} = 15V, I_D = 1.0A$		5	10	ns	
t _{d(off)}	Turn-Off Delay Time	$-V_{GS} = 10V, R_{GEN} = 6\Omega$		27	44	ns	
t _f	Fall Time			13	23	ns	
Qg	Total Gate Charge at 5V	$V_{GS} = 5V$		12	17	nC	
Q _{gs}	Gate to Source Gate Charge	V _{DD} = 15V		4		nC	
Q _{gd}	Gate to Drain "Miller" Charge			3		nC	
Drain-So	urce Diode Characteristics	• •					
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0V, I_S = 2A$ (Note 2)		0.9	1.2	V	
t _{rr}	Reverse Recovery Time			29		ns	
		— I _F = 11.5A, di/dt = 100A/μs		-		-	

Q_{rr}

Notes:
1: R_{0JA} is determined with the device mounted on a 1 in² oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0JA} is determined by the user's board design.
(a)R_{0JA} = 60°C/W when mounted on a 1 in² pad of 2 oz copper, 1.5'x1.5'x0.062' thick PCB.
(b)R_{0JA} = 135°C/W when mounted on a minimum pad of 2 oz copper.

 $I_F = 11.5A$, di/dt = 100A/µs

Reverse Recovery Charge



a. 60°C/W when mounted on a 1 in² pad of 2 oz copper



b. 135°C/W when mounted on a minimum pad of 2 oz copper

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2: Pulse Test: Pulse Width < 300µs, Duty cycle < 2.0%.

FDM6296 Rev.E

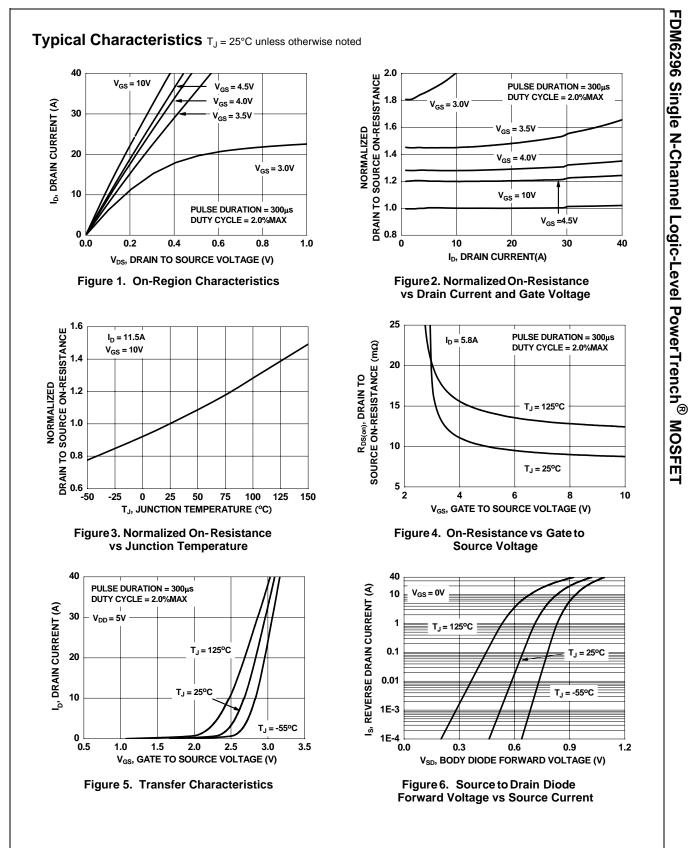
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nC

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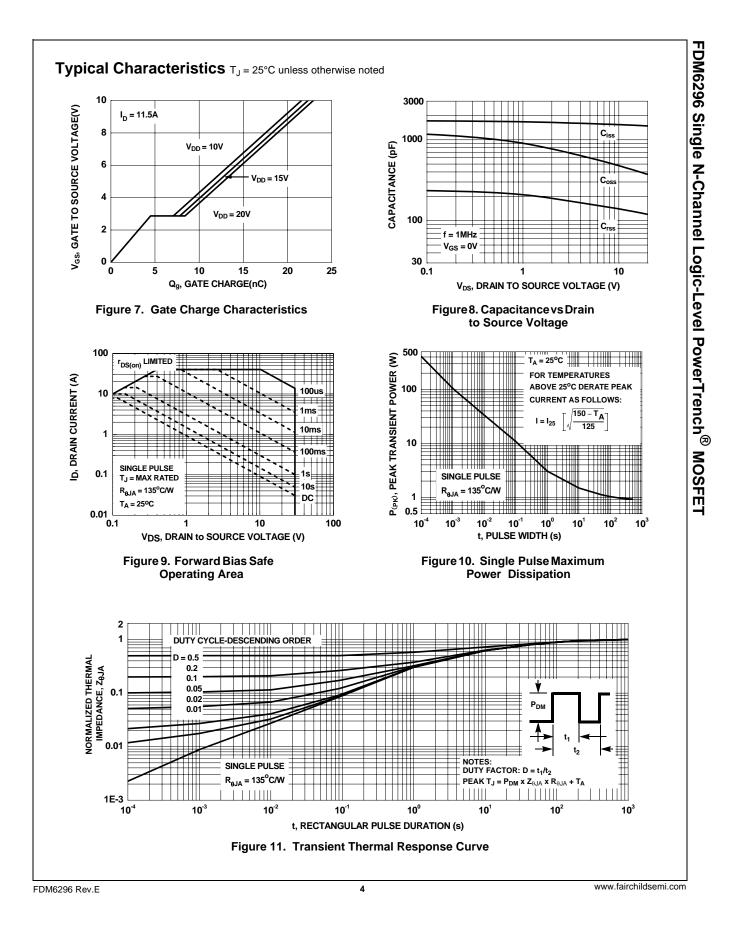
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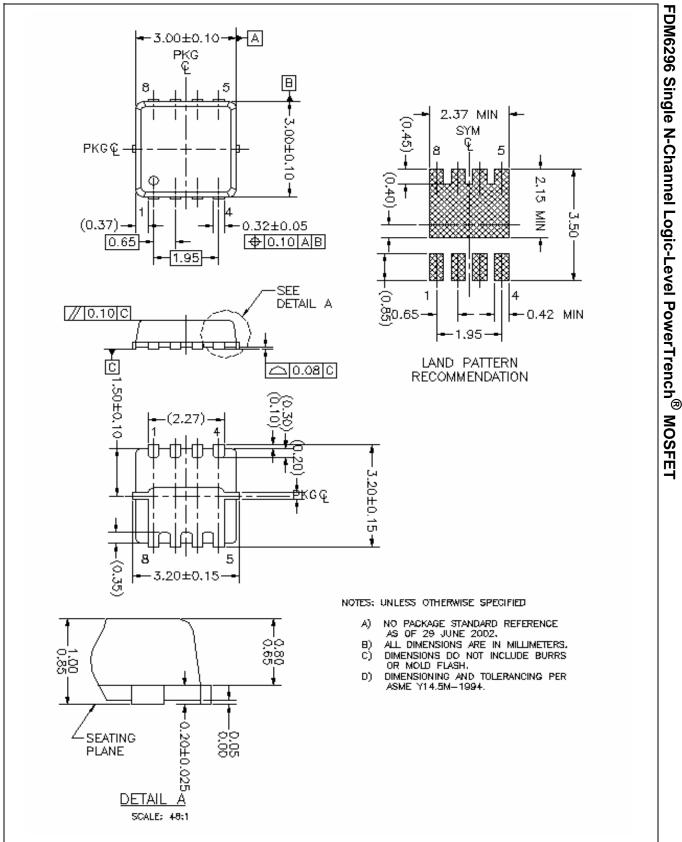
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